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MOS FIELD EFFECT POWER TRANSISTOR 2SK1284, 1284-Z

SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

The 2SK1284/1284-Z is N-channel MOS Field Effect Transistor designed for solenoid, motor and lamp driver.

FEATURES

- Low On-state Resistance
 RDS(on) ≤ 0.32 Ω (Vgs = 10 V, ID = 2 A)
- Built-in G-S Gate Protection Diode

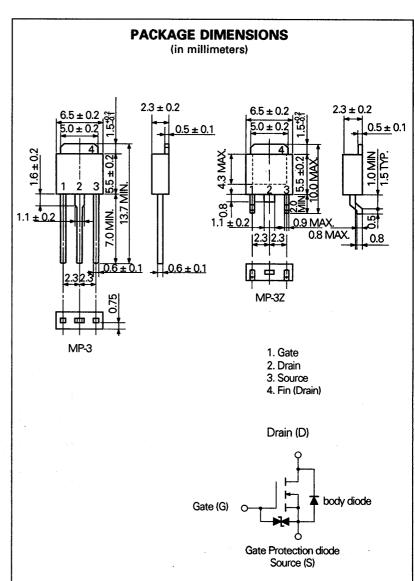
QUALITY GRADE

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

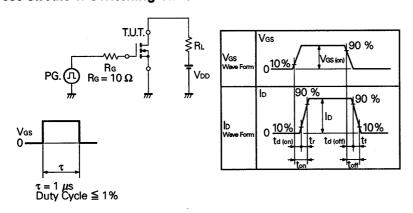
Drain to Source Voltage	Voss		100	٧
Gate to Source Voltage	VGSS(AC)	±20	٧
Drain Current (DC)	ID(DC)		±3.0	Α
Drain Current (pulse)	ID(pulse)	٠	±12	Α
Total Power Dissipation (Tc =	= 25 °C)	PT1	20	W
Total Power Dissipation (Ta =	= 25 °C)	PT2	1.0	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg	-55	to +150	°C
* PW \leq 10 μ s, Duty Cycle \leq 1 %	6			



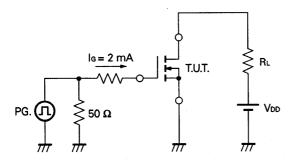
ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-state Resistance	RDS(on)		0.26	0.32	Ω	Vgs = 10 V, lp = 2 A
Drain to Source On-state Resistance	RDS(on)		0.32	0.40	Ω	Vgs = 4.0 V, lp = 2 A
Gate to Source Cutoff Voltage	VG8(off)	1.0		2.5	V	Vps = 10 V, lp = 1 mA
Forward Transfer Admittance	yfs	2.4			s	VD8 = 10 V, ID = 2 A
Drain Leakage Current	loss			10	μΑ	Vps = 100 V, Vgs = 0
Gate to Source Leakage Current	lgss			±10	μΑ	Vgs = ±20 V, Vps = 0
Input Capacitance	Ciss		500		pF	V _{DS} = 10 V V _{GS} = 0 f = 1 MHz
Output Capacitance	Coss		160		pF	
Reverse Transfer Capacitance	Cres		20		pF	
Turn-On Delay Time	td(on)		40		ns	$V_{GS(on)} = 10 \text{ V}$ $V_{DD} = 50 \text{ V}$ $I_{D} = 2 \text{ A, Rg} = 10 \Omega$ $RL = 25 \Omega$
Rise Time	tr		55		ns	
Turn-Off Delay Time	td(off)		500		ns	
Fall Time	tr		120		ns	
Total Gate Charge	Qc		13		nC	Vgs = 10 V lb = 3 A Vbb = 80 V
Gate to Source Charge	Qgs		3		nC	
Gate to Drain Charge	Qgp		2		nC	
Diode Forward Voltage	VsD		0.9		V	Iso = 3 A, Vgs = 0
Reverse Recovery Time	trr		140		ns	I _F = 3 A, V _{GS} = 0 di/dt = 50 A/μs
Reverse Recovery Charge	Qrr		250		nC	

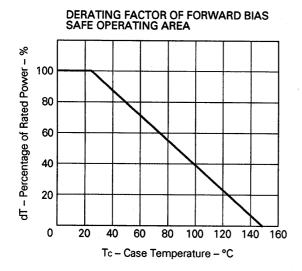
Test Circuit 1: Switching Time

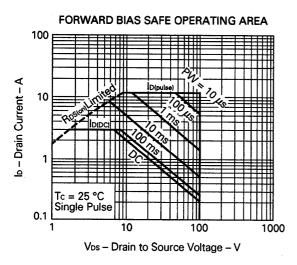


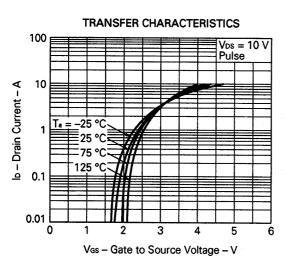
Test Circuit 2: Gate Charge

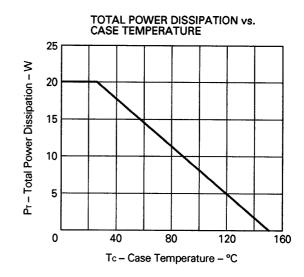


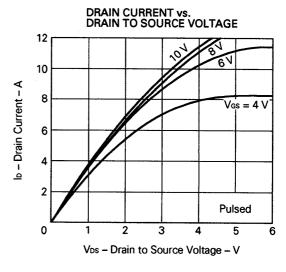
TYPICAL CHARACTERISTICS (Ta = 25 °C)

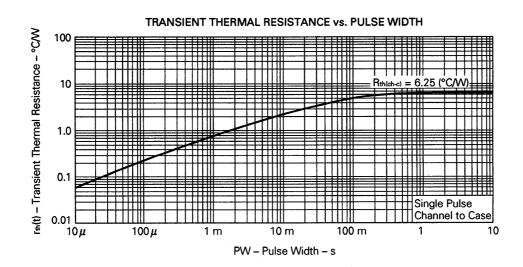


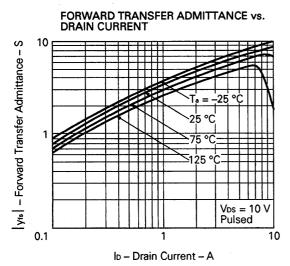


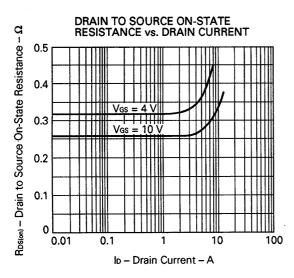


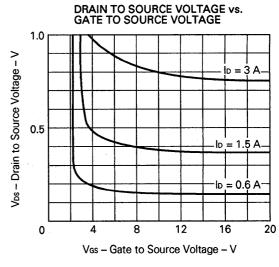


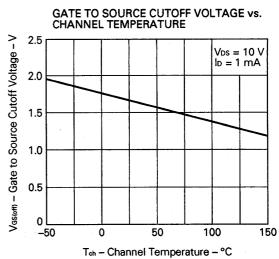


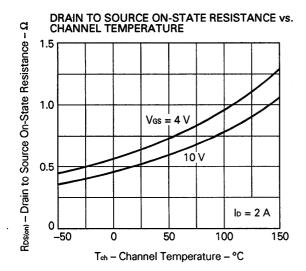


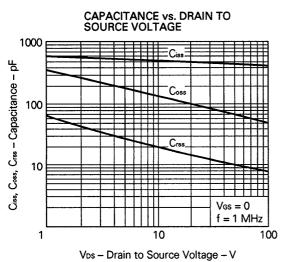


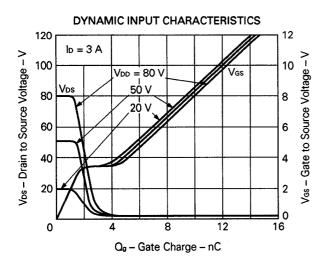


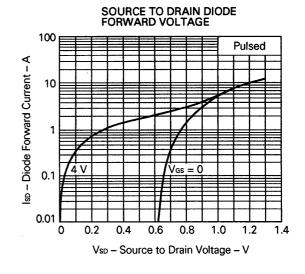


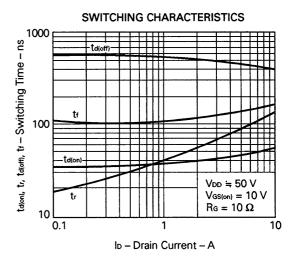


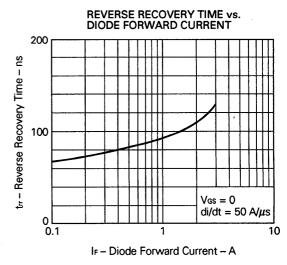












Reference

Application note name	No.
Safe operating area of Power MOS FET.	TEA-1034
Application circuit using Power MOS FET.	TEA-1035
Quality control of NEC semiconductors devices.	TEI-1202
Quality control guide of semiconductors devices.	MEI-1202
Assembly manual of semiconductors devices.	IEI-1207

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